

High Speed, Precision
 JFET Input Operational Amplifier

FEATURES

- **Guaranteed Slew Rate** $23V/\mu s$ Min.
- **Guaranteed Offset Voltage** $250\mu V$ Max.
- $-55^{\circ}C$ to $125^{\circ}C$ $750\mu V$ Max.
- **Guaranteed Drift** $5\mu V/\text{ }^{\circ}C$ Max.
- **Guaranteed Bias Current**
- $70^{\circ}C$ $180pA$ Max.
- $125^{\circ}C$ $4nA$ Max.
- **Gain-Bandwidth Product** $8.5MHz$ Typ.
- **Settling Time to 0.05% (10V Step)** $0.9\mu s$ Typ.

DESCRIPTION

The LT1022 JFET input operational amplifier combines high speed and precision performance.

A $26V/\mu s$ slew rate and $8.5MHz$ gain-bandwidth product are simultaneously achieved with offset voltage of typically $80\mu V$, $1.5\mu V/\text{ }^{\circ}C$ drift, bias currents of $50pA$ at $70^{\circ}C$, $500pA$ at $125^{\circ}C$. The output delivers $20mA$ of load current without gain degradation.

The $250\mu V$ maximum offset voltage specification represents less than $\frac{1}{2}$ least significant bit error in a 14-bit, 10V system.

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APPLICATIONS

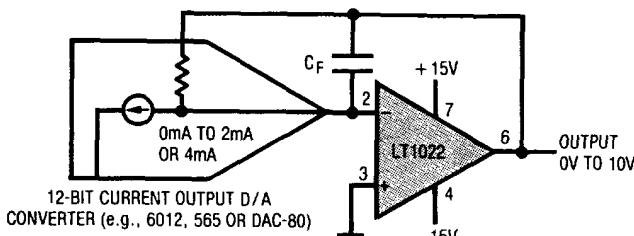
- Fast D/A Output Amplifiers (12, 14, 16 Bits)
- High Speed Instrumentation
- Fast, Precision Sample and Hold
- Voltage-to-Frequency Converters
- Logarithmic Amplifiers

The LT1022A meets or exceeds all OP-16A and OP-16E specifications. It is faster and more accurate without stability problems at cold temperatures.

The LT1022 can be used as the output amplifier for 12-bit current output D/A converters, as shown below.

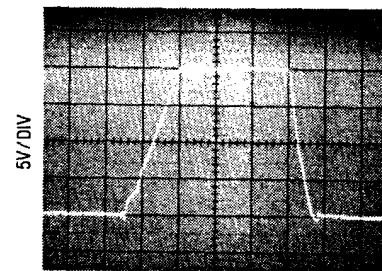
For a more accurate, lower power dissipation, but slower JFET input op amp, please refer to the LT1055 data sheet.

12-Bit Voltage Output D/A Converter



$C_F = 15pF$ TO $33pF$
 SETTLING TIME TO 2mV (0.8 LSB) = $1.5\mu s$ TO $2\mu s$

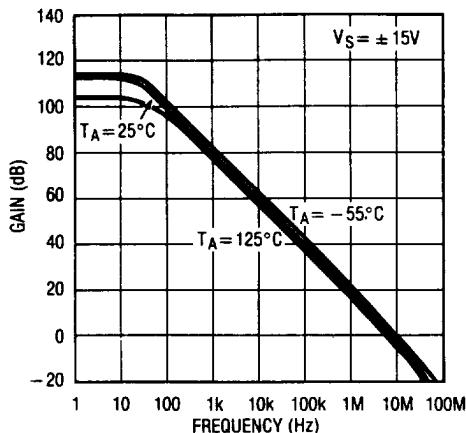
Large Signal Response



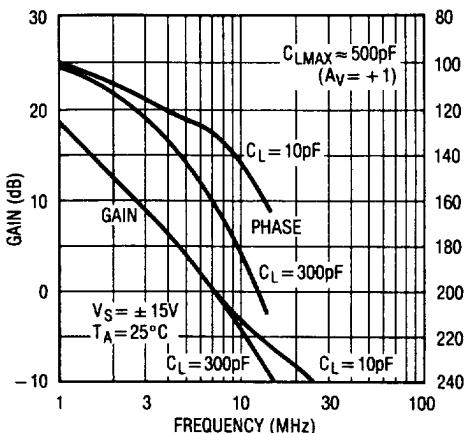
$A_V = 1$, $C_L = 100pF$, $0.5\mu s/DIV$
 $T_A = 25^{\circ}C$, $V_S = \pm 15V$

TYPICAL PERFORMANCE CHARACTERISTICS

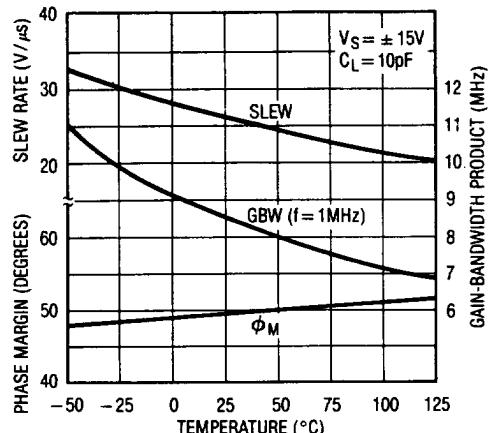
Gain vs Frequency



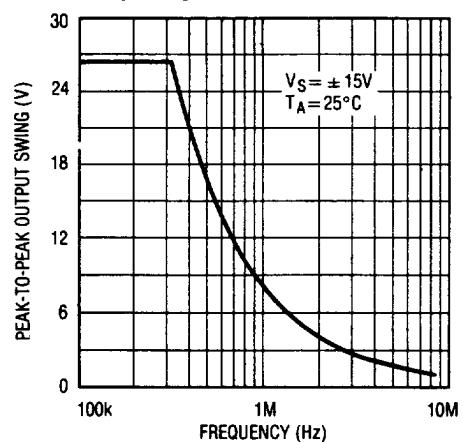
Gain, Phase Shift vs Frequency



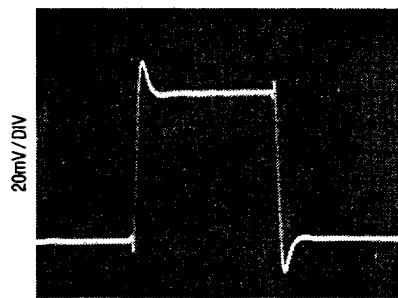
Phase Margin, Gain Bandwidth Product, Slew Rate vs Temperature



Undistorted Output Swing vs Frequency

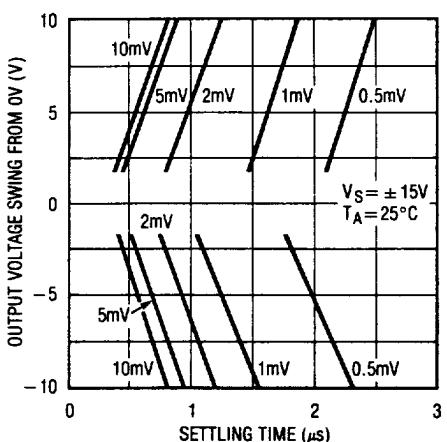


Small Signal Response



$A_V = +1, C_L = 100\text{pF}, 0.2\mu\text{s}/\text{DIV}$
 $T_A = 25^\circ\text{C}, V_S = \pm 15\text{V}$

Settling Time



The typical behavior of many LT1022 parameters is identical to the LT1056. Please refer to the LT1055 / 1056 data sheet for the following typical performance characteristics:

- Input Bias and Offset Currents vs Temperature
- Input Bias Current Over the Common-Mode Range
- Distribution of Input Offset Voltage (H and N8 Package)
- Distribution of Offset Voltage Drift with Temperature
- Warm-Up Drift
- Long Term Drift of Representative Units
- 0.1Hz to 10Hz Noise
- Voltage Noise vs Frequency
- Noise vs Chip Temperature

- Output Impedance vs Frequency
- Common-Mode Range vs Temperature
- Common-Mode and Power Supply Rejections vs Temperature
- Common-Mode Rejection Ratio vs Frequency
- Power Supply Rejection Ratio vs Frequency
- Voltage Gain vs Temperature
- Supply Current vs Supply Voltage
- Output Swing vs Load Resistance
- Short Circuit Current vs Time

APPLICATIONS INFORMATION

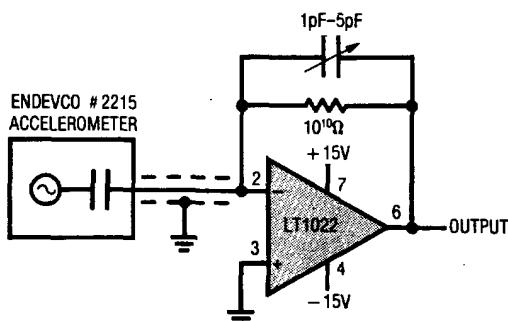
The LT1056 applications information is directly applicable to the LT1022. Please consult the LT1055/1056 data sheet for details on:

- (1) plug-in compatibility to industry standard devices
- (2) offset nulling
- (3) achieving picoampere/microvolt performance

- (4) phase-reversal protection
- (5) high speed operation (including settling time test circuit)
- (6) noise performance
- (7) simplified circuit schematic.

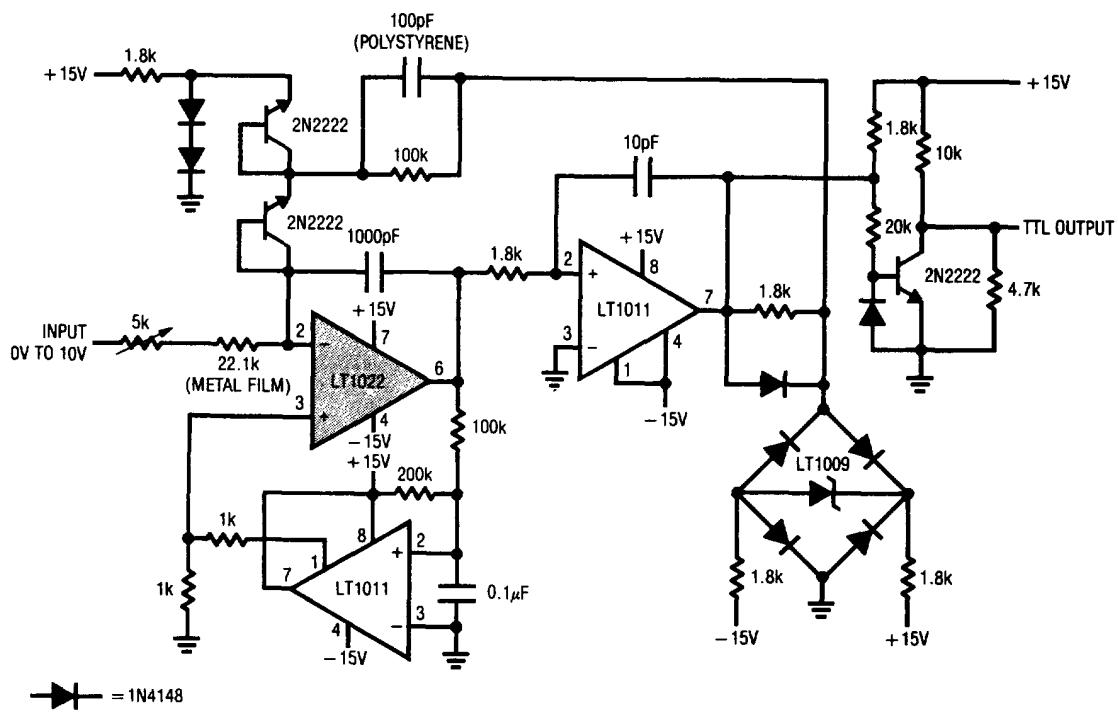
TYPICAL APPLICATIONS

Fast Piezoelectric Accelerometer



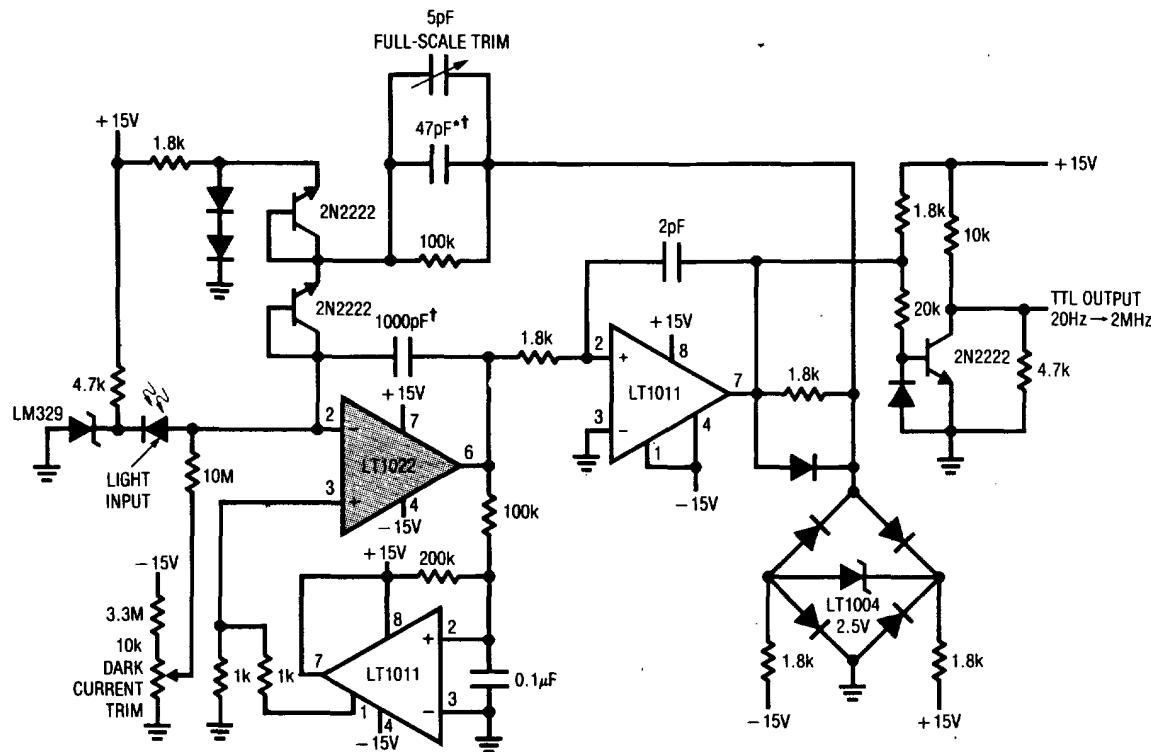
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10Hz to 1MHz Voltage-to-Frequency Converter



TYPICAL APPLICATIONS

A Photodiode-to-Frequency Converter



SCALE FACTOR =
1nW/Hz AT 900 NANOMETERS FROM 20nW TO 2mW

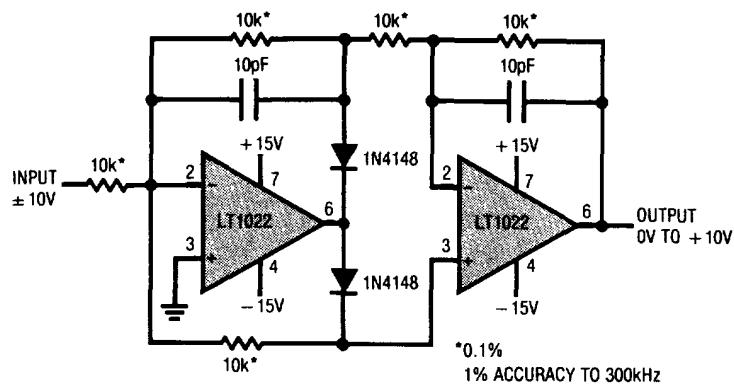
\downarrow = HEWLETT PACKARD PHOTODIODE HP5082-4204

► = 1N4148

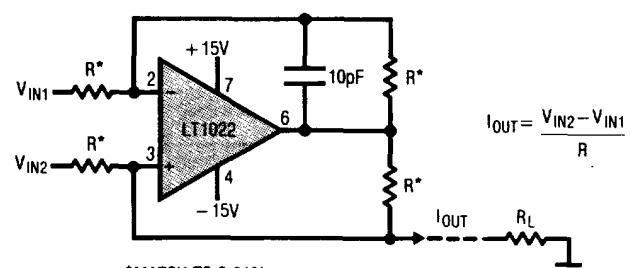
†POLYSTYRENE

*SELECT VALUE FOR 2mW IN = 2MHz OUT.

Wide Bandwidth Absolute Value Circuit



Fast, Differential Input Current Source



*MATCH TO 0.01%

FULL-SCALE POWER BANDWIDTH

= 1MHz FOR $I_{OUT}R = 8Vp-p$

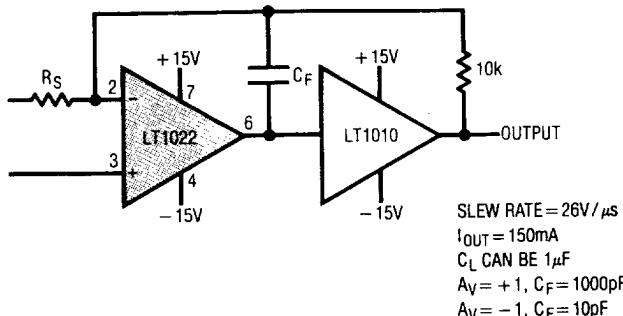
= 400kHz FOR $I_{OUT}R = 20Vp-p$

MAXIMUM $I_{OUT} = 10mA$

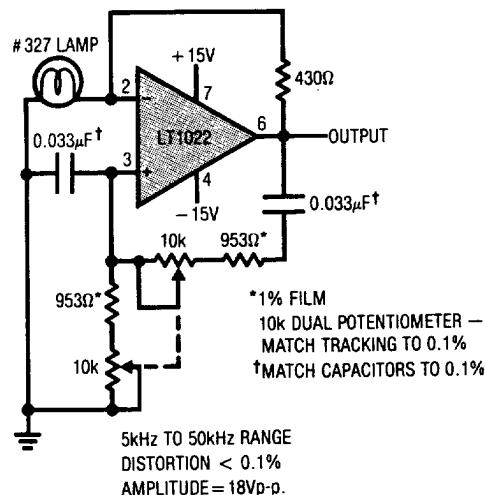
COMMON-MODE VOLTAGE AT LT1022 INPUT = $\frac{I_{OUTp-p} \times R_L}{2}$

TYPICAL APPLICATIONS

High Output Current Op Amp

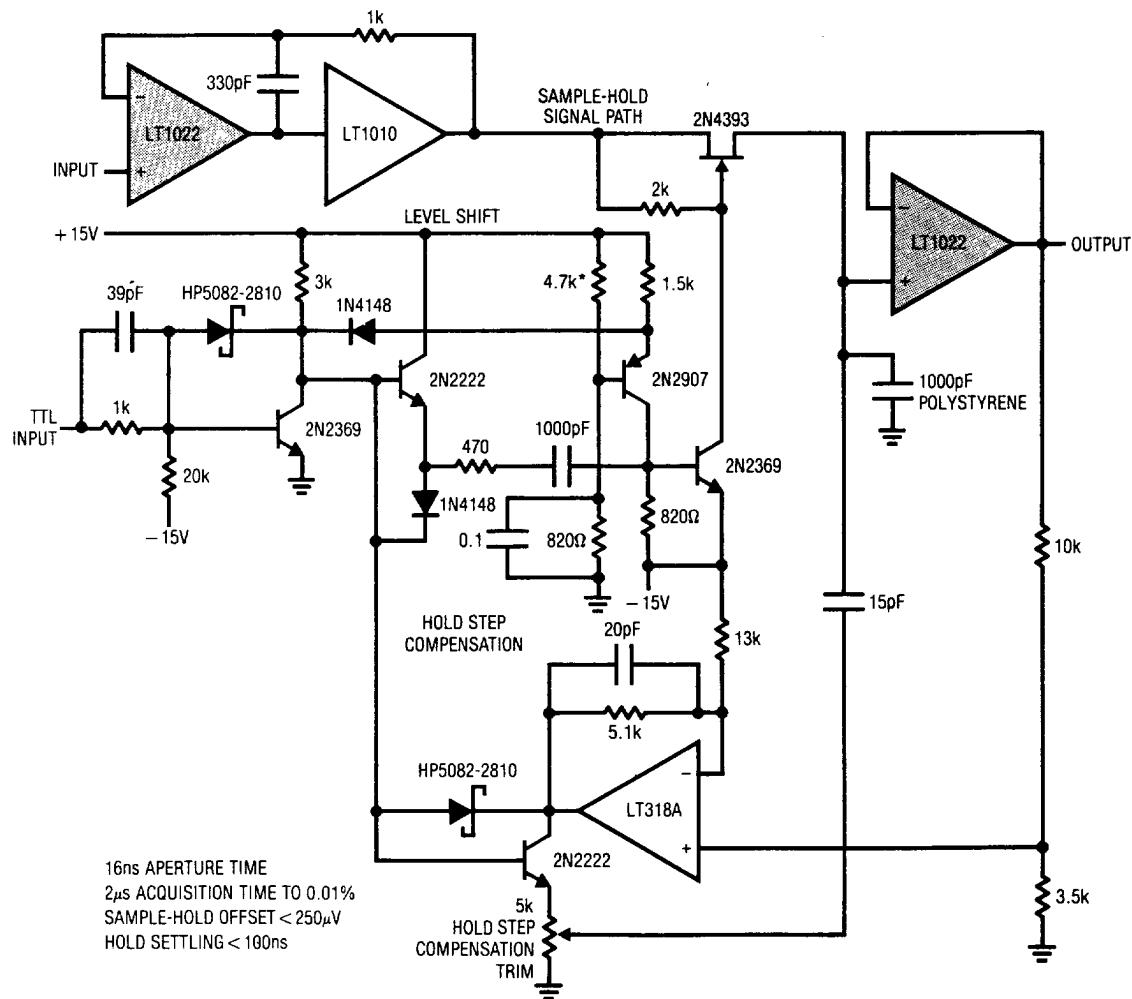


Low Distortion Sine Wave Oscillator



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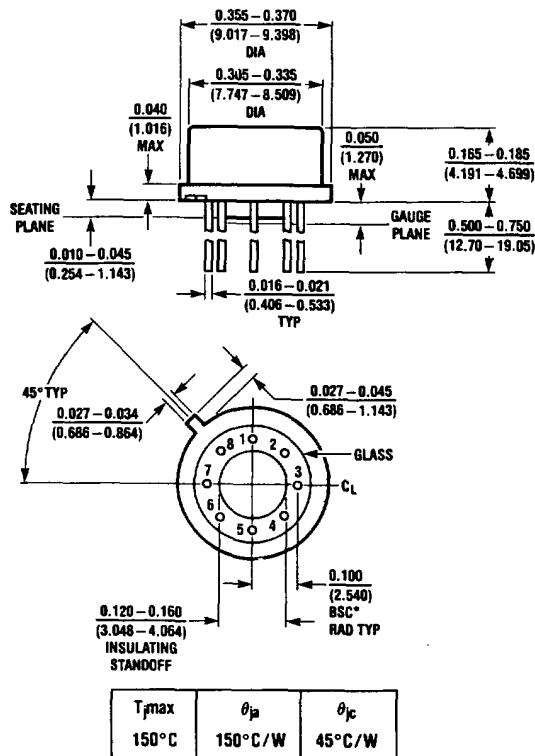
Fast, Precision Sample-Hold



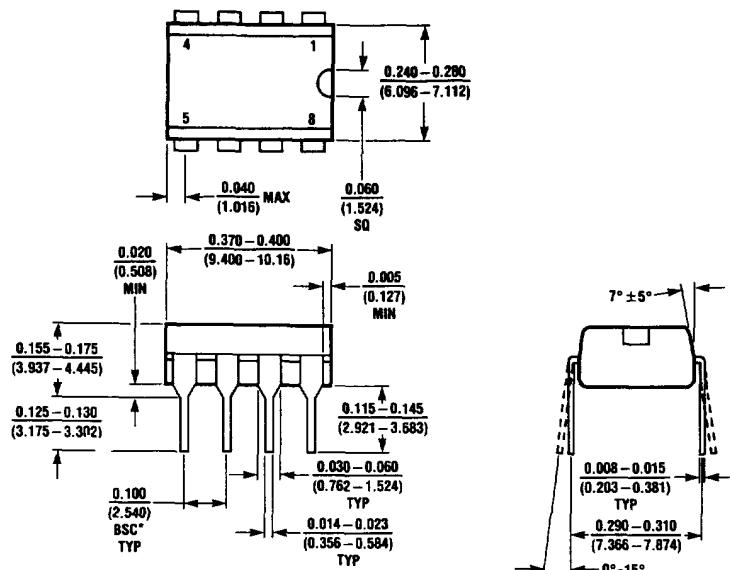
PACKAGE DESCRIPTION

Dimensions in inches (millimeters) unless otherwise noted.

H Package Metal Can



N8 Package 8 Lead Plastic



*LEADS WITHIN 0.007 OF TRUE POSITION (TP) AT GAUGE PLANE

T _{jmax} 100°C	θ _{ja} 130°C/W
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